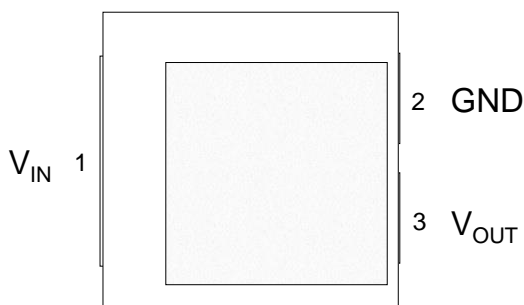
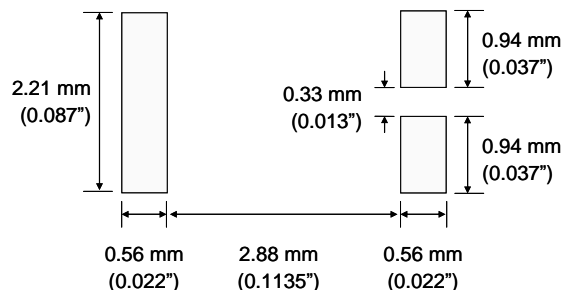


CONFIGURATION INFORMATION

Pin Configuration (Top View)



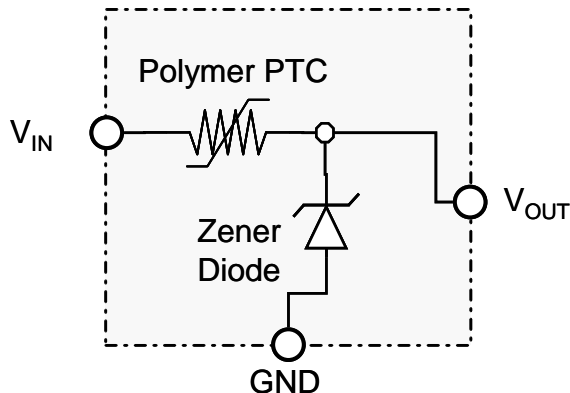
Recommended Pad Dimensions



PIN DESCRIPTION

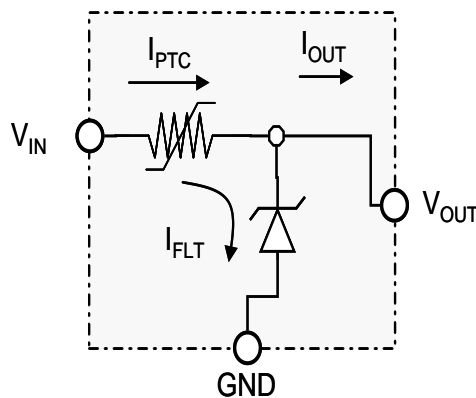
Pin Number	Pin Name	Pin Function
1	V _{IN}	V _{IN} . Protected input to Zener diode.
2	GND	GND
3	V _{OUT}	V _{OUT} . Zener regulated voltage output

BLOCK DIAGRAM



DEFINITION of TERMS

I _{PTC}	Current flowing through the PTC portion of the circuit
I _{FLT}	RMS fault current flowing through the diode
I _{OUT}	Current flowing out the V _{OUT} pin of the device
Trip Event	A condition where the PTC transitions to a high resistance state, thereby significantly limiting I _{PTC} and related currents, and significantly increasing the voltage drop between V _{IN} and V _{OUT} .
Trip Endurance	Time the PTC portion of the device remains both powered and in a tripped state.



GENERAL SPECIFICATIONS

Operating Temperature -40° to +85°C

Storage Temperature -40° to +85°C

ELECTRICAL CHARACTERISTICS^{1-3, 11} (Typical unless otherwise specified)

V _Z ⁴ (V)			I _{ZT} ⁴ (A)	I _{HOLD} ⁵ @20°C (A)	Leakage Current		R Typ ⁶ (Ohms)	R _{1Max} ⁷ (Ohms)	V _{INT} Max ⁸ (V)		I _{FLT} Max ⁹		Tripped Power Dissipation ¹⁰ Max	
Min	Typ	Max			Test Voltage	Max Current (mA)			V _{INT} Max (V)	Test Current (A)	I _{FLT} Max (A)	Test Voltage (V)	Value (W)	Test Voltage (V)
16.1	16.4	16.6	0.1	1.3	16	5	0.12	0.16	24V	3A	+1.25 -40	+24 -16V	1.0	24

Note 1: Electrical characteristics determined at 25°C unless otherwise specified.

Note 2: This device is intended for limited fault protection. Repeated trip events or extended trip endurance can degrade the device and may affect performance to specifications. Performance impact will depend on multiple factors including, but not limited to, voltage, trip current, trip duration, trip cycles, and circuit design. For details or ratings specific to your application contact Littelfuse Circuit Protection directly.

Note 3: Specifications developed using 1.0 ounce 0.045" wide copper traces on dedicated FR4 test boards. Performance in your application may vary.

Note 4: I_{ZT} is the current at which V_Z is measured (V_Z = V_{OUT}). Additional V_Z values are available on request.

Note 5: I_{HOLD}: Maximum steady state I_{PTC} (current entering or exiting the V_{IN} pin of the device) that will not generate a trip event at the specified temperature. Specification assumes I_{FLT} (current flowing through the Zener diode) is sufficiently low so as to prevent the diode from acting as a heat source. Testing is conducted with an "open" Zener.

Note 6: R Typ: Resistance between V_{IN} and V_{OUT} pins during normal operation at room temperature.

Note 7: R_{1Max}: The maximum resistance between V_{IN} and V_{OUT} pins at room temperature, one hour after 1st trip or after reflow soldering.

Note 8: V_{INT} Max: V_{INT} Max relates to the voltage across the PPTC portion of the PolyZen device (V_{IN}-V_{OUT}). V_{INT} Max is defined as the voltage (V_{IN}-V_{OUT}) at which typical qualification devices (98% devices, 95% confidence) survived at least 100 trip cycles and 24 hours trip endurance at the specified voltage (V_{IN}-V_{OUT}) and current (I_{PTC}). V_{INT} Max testing is conducted using a "shorted" load (V_{OUT} = 0V). V_{INT} Max is a survivability rating, not a performance rating.

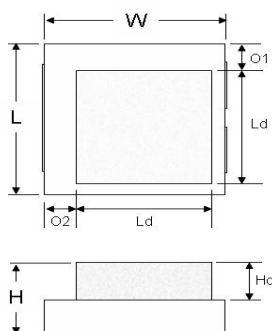
Note 9: I_{FLT} Max: I_{FLT} Max relates to the steady state current flowing through the diode portion of the PolyZen device in a fault condition, prior to a trip event. I_{FLT} Max is defined as the current at which typical qualification devices (12 parts per lot from 3 lots) survived 100 test cycles. RMS fault currents above I_{FLT} Max may permanently damage the diode portion of the PolyZen device. Testing is conducted with **NO** load connected to V_{OUT}, such that I_{OUT} = 0.

"Test voltage" is defined as the voltage between V_{IN} to GND and includes the PolyZen Diode drop. Specification is dependent on the direction of current flow through the diode. I_{FLT} Max is a survivability rating, not a performance rating.

Note 10: The power dissipated by the device when in the "tripped" state, as measured on Littelfuse test boards (see note 3).

Note 11: Specifications based on limited qualification data and subject to change.

MECHANICAL DIMENSIONS



		Min	Typical	Max
Length	L	3.85 mm (0.152")	4 mm (0.16")	4.15 mm (0.163")
Width	W	3.85 mm (0.152")	4 mm (0.16")	4.15 mm (0.163")
Height	H	1.4mm (0.055")	1.7 mm (0.067")	2.0 mm (0.081")
Length Diode	Ld	-	3.0 mm (0.118")	-
Height Diode	Hd	-	1.0 mm (0.039")	-
Offset	O1	-	0.6 mm (0.024")	-
Offset	O2	-	0.7 mm (0.028")	-

SOLDER REFLOW RECOMMENDATIONS:

Classification Reflow Profiles

Profile Feature

Average Ramp-Up Rate (T_{smax} to T_p)

Pb-Free Assembly

3° C/second max.

Preheat

- Temperature Min (T_{smin})
- Temperature Max (T_{smax})
- Time (t_{smin} to t_{smax})

150 °C
200 °C
60-180 seconds

Time maintained above:

- Temperature (T_L)
- Time (t_L)

217 °C
60-150 seconds

Peak/Classification Temperature (T_p)

260 °C

Time within 5 °C of actual Peak

Temperature (t_p)

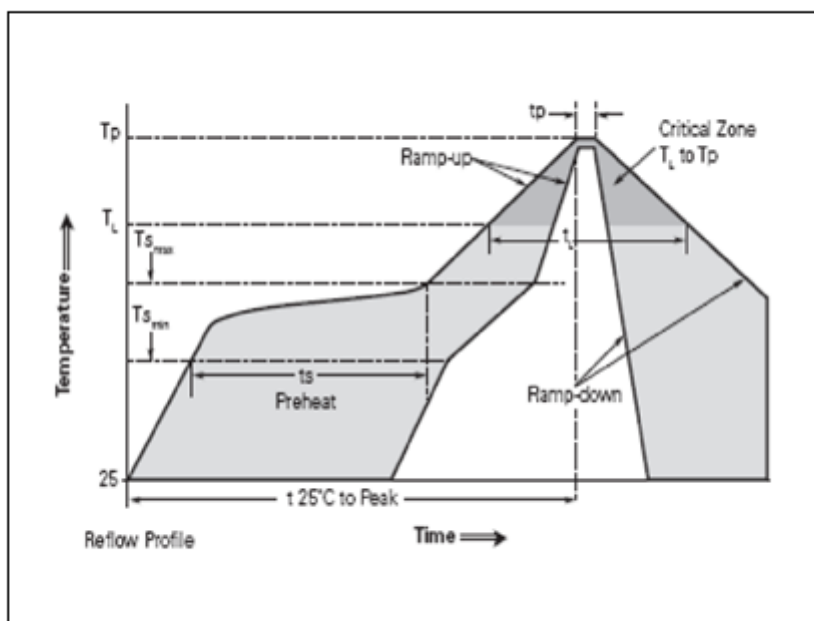
20-40 seconds

Ramp-Down Rate

6 °C/second max.

Time 25 °C to Peak Temperature

8 minutes max.



PACKAGING

Packaging	Tape & Reel	Standard Box
ZENXXXVXXXAXXLS	3,000	15,000

Reel Dimensions for PolyZen Devices

$A_{\max} = 330$
 $N_{\min} = 102$
 $W_1 = 8.4$
 $W_2 = 11.1$



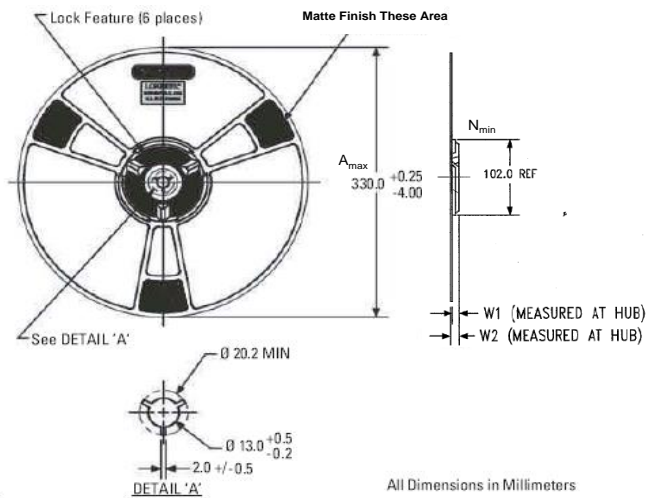
Expertise Applied | Answers Delivered

PolyZen

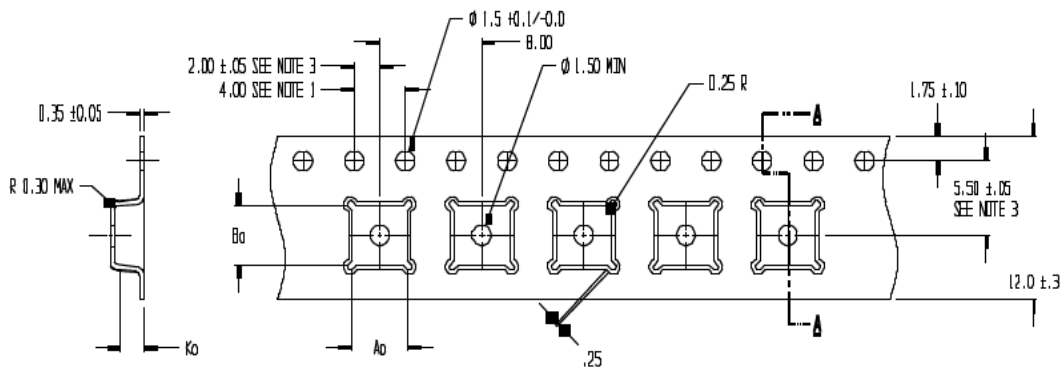
Polymer Enhanced Zener Diode
Micro-Assemblies

PRODUCT : ZEN164V130A24LS

DOCUMENT: SCD27330
REV LETTER: D
REV DATE: JULY 26, 2016
PAGE NO.: 6 OF 10



Taped Component Dimensions for PolyZen Devices



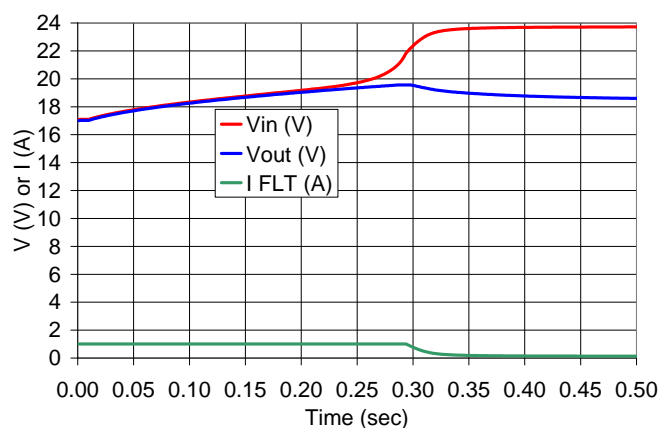
NOTES:

1. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ± 0.2
2. CAMBER IN COMPLIANCE WITH EIA 481
3. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE

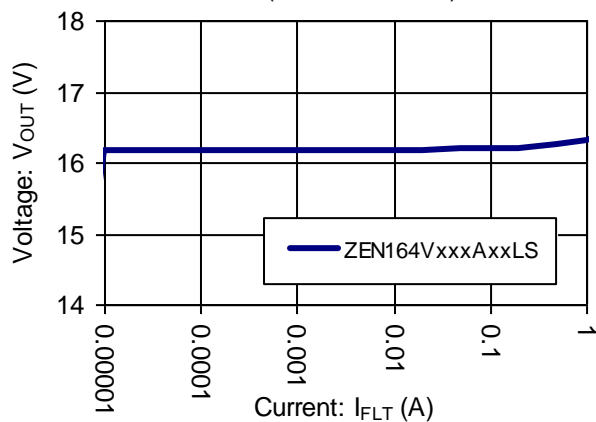
$Aa = 4.35$
 $Ba = 4.35$
 $Ka = 2.30$

TYPICAL CHARACTERISTICS

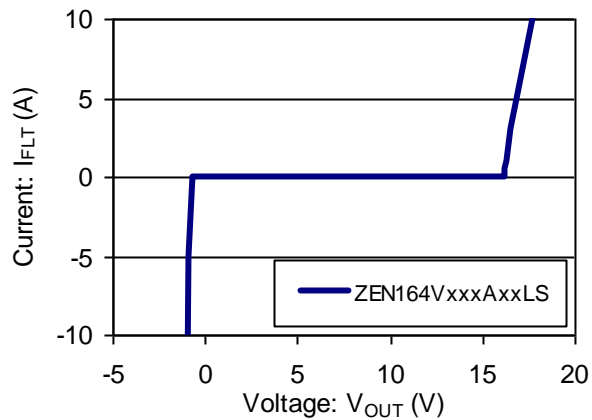
Typical Fault Response: ZEN164V130A24LS
24 V/1.0 A Current Limited Source ($I_{out}=0$)

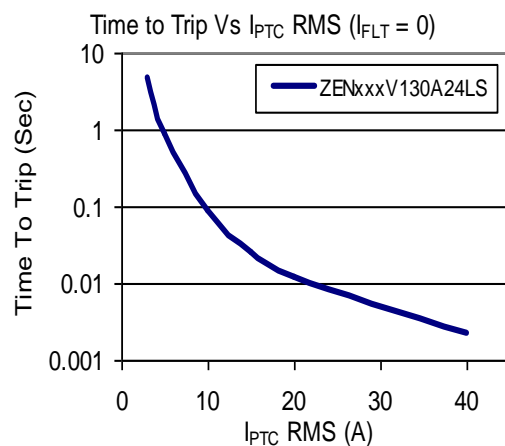
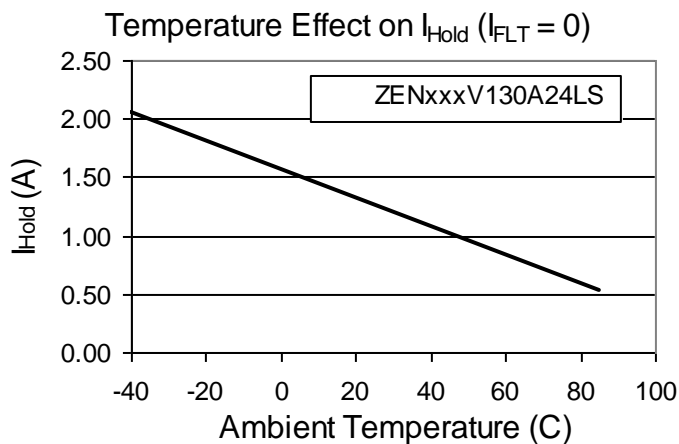
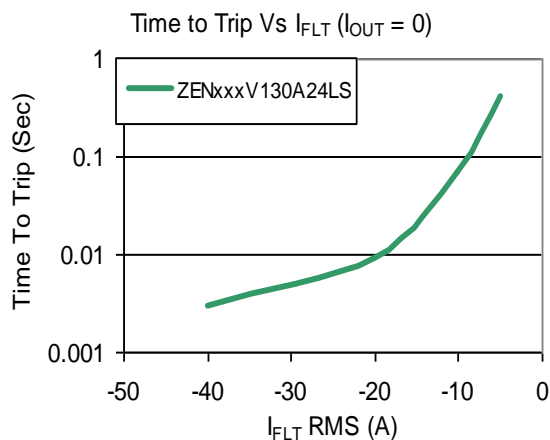
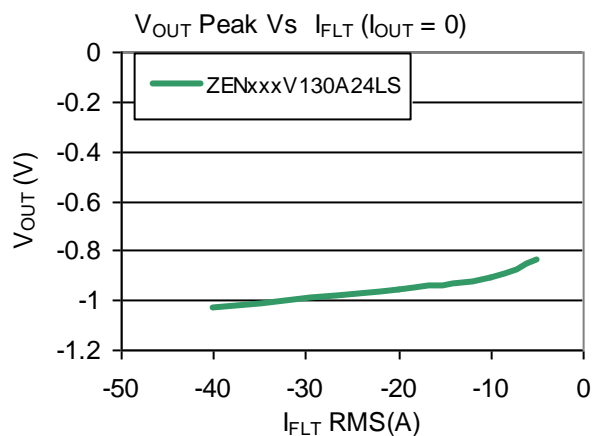
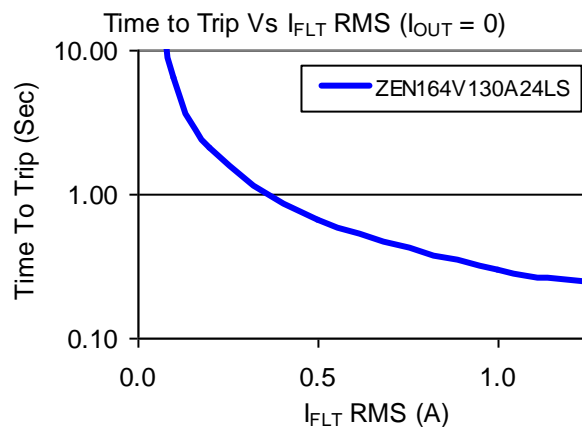
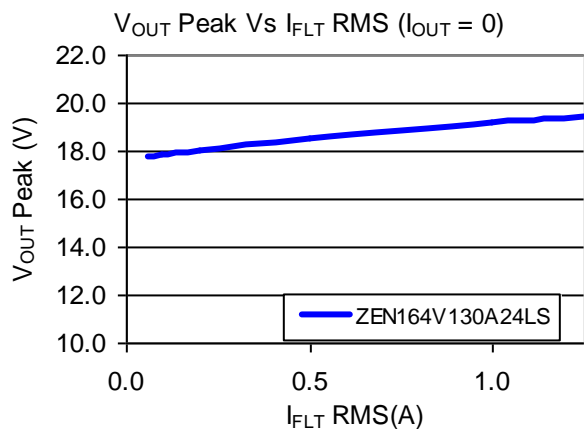


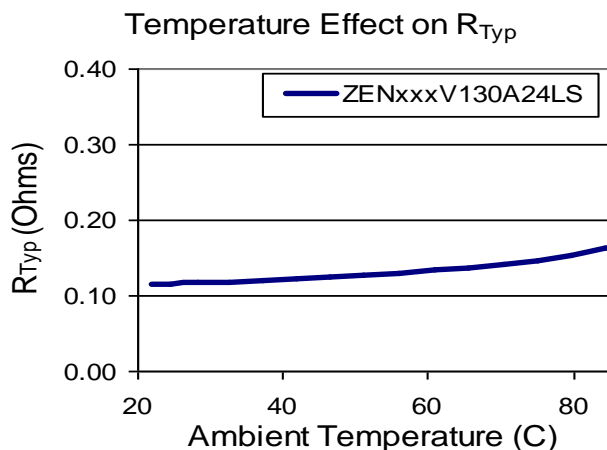
Pulse IV (100uSec Pulse)



Pulse IV (100uSec Pulse)







Materials Information

ROHS Compliant

Directive 2002/95/EC
Compliant

ELV Compliant

Directive 2000/53/EC
Compliant

Pb-Free



Halogen Free*



* Halogen Free refers to: $Br \leq 900ppm$, $Cl \leq 900ppm$, $Br+Cl \leq 1500ppm$.

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